

Ansaldo Trasporti s.p.a. Unita' Semiconduttori

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FAST RECOVERY DIODE

ARF340

Repetitive voltage up to 2600 V

Mean forward current 775 A

Surge current 6.4 kA

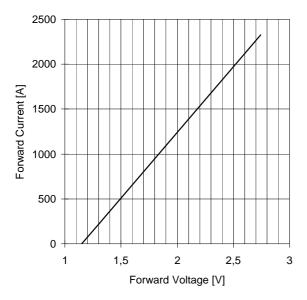
FINAL SPECIFICATION

lug 98 - ISSUE : 01

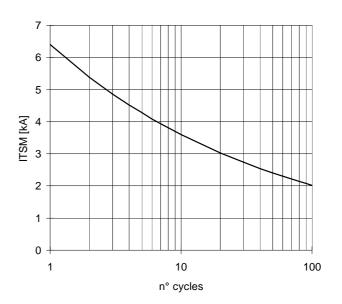
Symbol	Characteristic	Conditions	Tj [°C]	Value	Unit
BLOCK	KING				
V RRM	Repetitive peak reverse voltage		150	2600	V
V RSM	Non-repetitive peak reverse voltage		150	2700	V
I RRM	Repetitive peak reverse current	V=VRRM	150	50	mA
CONDU	JCTING				
l F(AV)	Mean forward current	180° sin ,50 Hz, Th=55°C, double side cooled		775	А
I F (AV)	Mean forward current	180° square,50 Hz,Th=55°C,double side cooled		780	А
l FSM	Surge forward current	Sine wave, 10 ms	150	6,4	kA
l² t	2 t	reapplied reverse voltage up to 50% VRSM		205 x1E3	A²s
V FM	Forward voltage	Forward current : 1200 A	25	2,3	V
				4.45	.,
V F(TO)	Threshold voltage		150	1,15	V
V F(TO)	Threshold voltage Forward slope resistance		150 150	0,685	mohm
	Forward slope resistance				
rF	Forward slope resistance	IF = 350 A			
r F SWITC	Forward slope resistance HING	I F = 350 A di/dt= 80 A/μs		0,685	mohm
SWITC	Forward slope resistance HING Reverse recovery time		150	0,685	mohm
SWITC	Forward slope resistance HING Reverse recovery time Reverse recovery charge	di/dt= 80 A/μs	150	0,685 4 260	mohm μs μC
SWITC t rr Q rr	Forward slope resistance HING Reverse recovery time Reverse recovery charge Peak reverse recovery current	di/dt= 80 A/μs	150	0,685 4 260 140	mohm μs μC
SWITC t rr Q rr I rr	HING Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Peak forward recovery	di/dt= 80 A/μs VR = 100 V	150	0,685 4 260 140 0,4	mohm μs μC A
SWITC t rr Q rr I rr s	HING Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Peak forward recovery	di/dt= 80 A/μs VR = 100 V	150	0,685 4 260 140 0,4	mohm μs μC Α
SWITC t rr Q rr I rr s V FR	HING Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Peak forward recovery	di/dt= 80 A/μs VR = 100 V di/dt= 400 A/μs	150	0,685 4 260 140 0,4 20	mohm μs μC Α
SWITC t rr Q rr I rr s V FR MOUN	HING Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Peak forward recovery TING Thermal impedance	di/dt= 80 A/μs VR = 100 V di/dt= 400 A/μs	150	0,685 4 260 140 0,4 20	mohm μs μC Α

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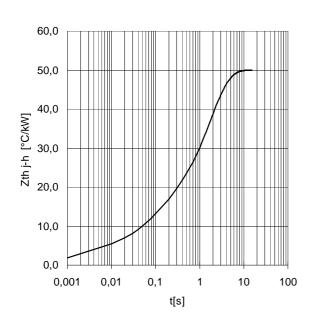
FORWARD CHARACTERISTIC Tj = 150 °C

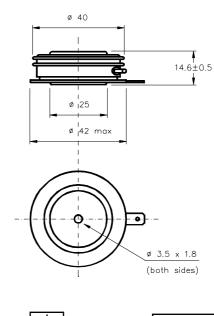


SURGE CHARACTERISTIC Tj = 150 °C



TRANSIENT THERMAL IMPEDANCE DOUBLE SIDE COOLED







All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness < .03 mm and roughness < 2 μ m.

In the interest of product improvement ANSALDO reserves the right to change any data given in this data sheet at any time without previous notice.

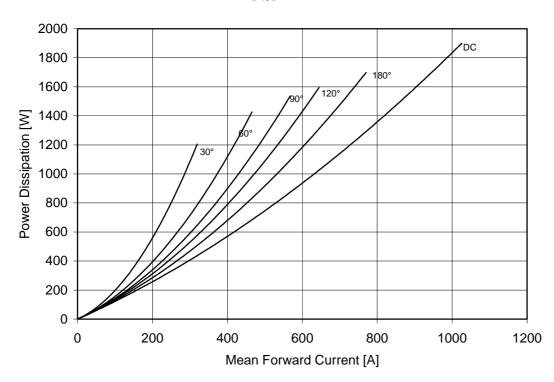
If not stated otherwise the maximum value of ratings (simbols over shaded background) and characteristics is reported.

Distributed by

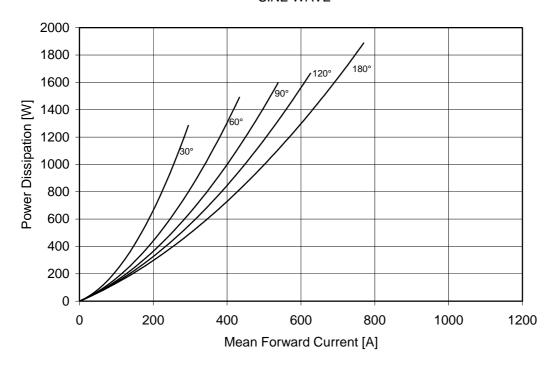
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DISSIPATION CHARACTERISTICS

SQUARE WAVE



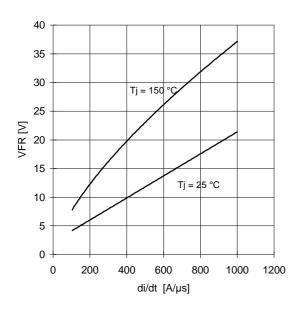
SINE WAVE

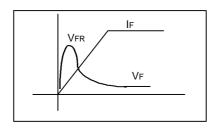


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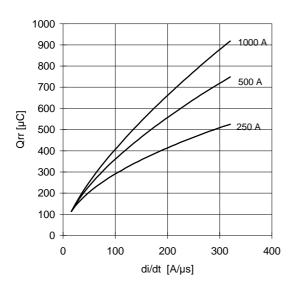
SWITCHING CHARACTERISTICS

FORWARD RECOVERY VOLTAGE

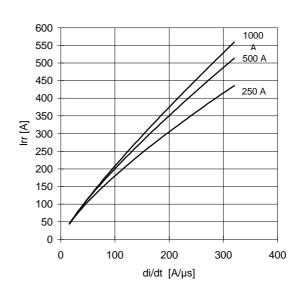




REVERSE RECOVERY CHARGE Tj = 150 °C



REVERSE RECOVERY CURRENT Tj = 150 °C



$$ta = Irr / (di/dt)$$

tb = trr - ta

Softness (s factor) s = tb / ta

Energy dissipation during recovery Er = Vr (Qrr - Irr ta /

